

Module 4: Ensuring Package Reliability: Testing & Performance Evaluation

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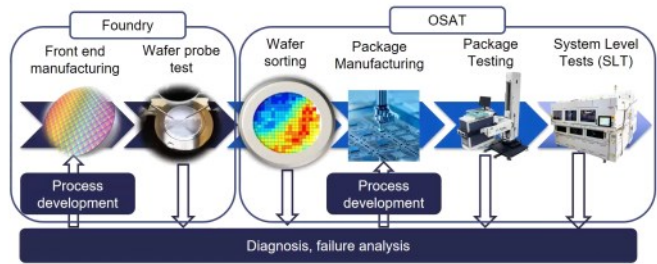
L1: Introduction to Package Testing & Electrical Functionality Checks

This is done after the package has been manufactured.
Must test package electrically after optical tests have been carried out.

Wafer Mapping: Must map out all the good dies from the wafer in order to avoid spending resources to packages faulty dies. Done by wafer probing & at foundry or at OSAT

Post package manufacturing, we move to package testing & board level testing after product assembly.

Diagnosis & failure analysis helps us understand why failure occurs & how can it be improved.
Useful in improving yield.



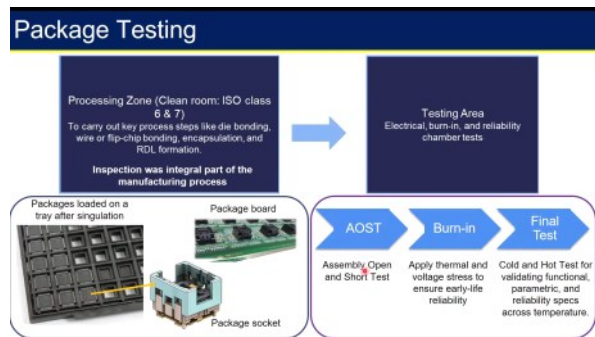
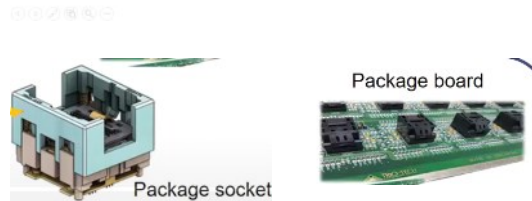
Package Testing:

Now IC has been packages in the clean rooms & inspection has been carried out.
The ICs are then moved to the testing floor, which may not have as stringent cleanliness standards like a clean room.

Testing for the packaged systems is done on a package socket on package boards.

After singulation, we carry out a variety tests:

1. AOST: Assembly Open & Short test (Detects opens & shorts)
2. Burn-in: Apply thermal & voltage stress to ensure early-life reliability (Testing on stress application)
3. Final Test: Cold & Hot test for functionality, parametric tests, reliability across temp ranges etc. (Performance analysis under temp cycling)



Assembly Open & Short Test (AOST):

Objective: Test for shorts or opens on package solder balls or leads.
Done after singulation or lead trim or form.

ICs are check for open/short testing.

Can have issues like:

1. Head on Pillow Open (HoP Open)
2. Head On Pillow (HoP)
3. Bridging
4. Non Wet Open
5. Die Cracks
6. Package warping

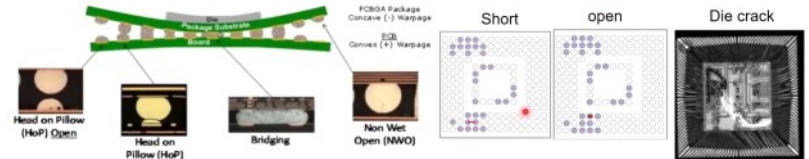
Product grouped into:

1. Best
2. Better
3. Scrap

Assembly Open and Short Test (AOST) - Functionality

Objective: Quick test for shorts or opens on package leads or balls.

- Testing immediately follows Trim and Form (lead frame packages) or Singulation (BGA packages).
- The packages are put through an open/short test to screen for massive electrical fails before leaving assembly.
- There is also a vision inspection to check for damaged or missing balls/leads and other obvious defects
- Product Grade Sort (PGSRT) catches Assembly related fails, and sorts into Product Grades: Best (1), Better (2), Better (3), Scrap (4).



L2: Reliability & Performance Testing of Semiconductor Packages

Burn - In Test: Tests packages under elevated conditions in terms of voltage, temperature, power & cycling.

Helps identify chips that may fail prematurely

Parts are loaded into burn-in trays & tested under elevated temps, voltage which helps catch initial failures.

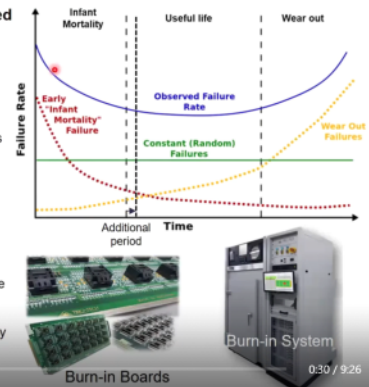
Prominent defects caught in this stage: Metallization Failure, Electromigration.
But shortens overall lifespan.

We have some finite failure rate even if a chip survives the burn-in.

Burn-in Test

Objective: Testing of package components under elevated (stressful) conditions. temperature, voltage, and power cycling

- The goal of Burn-in is to identify "Infant Mortality" failures before it reaches the customer.
- Parts are loaded from trays onto Burn-in boards and then, into ovens (Burn-in system) during testing.
- Burn-in accelerates the failures by applying high voltage and high temperature stress.
- The test is carried out long enough to catch the initial rate of failures and then to test slightly over the point where the curve flattens out.
- Defects like dielectric & metallization failures, electromigration can be detected during burn-in.
- Although it removes the unreliable components with a high probability of early failure, the total life span of components is shortened with a burn-in test.



Final Test:
Corner tests to verify that packaged die meets specs.

Use a temp controlled environment:

1. Hot Test: Elevated temps.
2. Cold Test: Parts are subjected to low temps.

ATE: Automatic Test Equipment.

Electrical Test Units & Handler (Placing DUT).

These test equipment send out automatic test patterns generation (ATPG) to a device under test (DUT).
Check for:

1. Parametric Tests: Measure current or voltage from units to ensure function within specified range
2. Functional Test: Test functioning under expected test conditions.
3. Speed Test: If device performs at desired speed.

KPIs: Yield, Test time & Coverage

They Have 2 distinct units:

1. Handler
2. In-Circuit Tester

Final Test

Objective: A temperature corner test to verify that the packaged product meets the specifications

ATE (Electrical Testing Unit) with Handler (Placing DUT)

- Parts are loaded into handler with temperature controlled test fixtures (not ovens) during testing.
- Hot Test: Elevated temperatures according to product specifications. Parts are electrically tested at high temperatures to verify if the specifications are met.
- Cold Test: Parts are subjected to low temperatures according to product specifications and electrically tested.



[LM741 OPamp \(TI\) Datasheet](#)

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) [†]0°C

PARAMETER	MIN	MAX	UNIT
Supply voltage	LM741, LM741A	±18	V
Power dissipation ^{††}	LM741C	500	mW
Offset input voltage	LM741	±100	V
Input voltage ^{††}	LM741	±18	V
Output short-circuit duration	LM741, LM741A	Continuous	
Operating temperature	LM741C	-50 — 125	°C
Storage temperature	LM741, LM741A	-50 — 125	°C
Junction temperature	LM741C	125	°C
Building information	POP package (10 seconds)	200	°C
Storage information	QFP or TQFP package (10 seconds)	200	°C
Storage temperature, T _{stg}		-65 — 150	°C

6.5 Electrical Characteristics, LM741^{††}

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input offset voltage	R _L ≥ 10 kΩ, T _A = 25°C		1	5	mV
Input offset voltage adjustment range	T _A = 25°C, V _{OS} = ±20 V		±15		mV
Input offset current	T _A = 25°C		20	200	nA
Input bias current	T _A = 25°C, T _{OS} = T _{max}		80	500	nA
Input resistance	T _A = 25°C, V _I = 0 V		0.9	2	MΩ
Input voltage range	T _A = 25°C, V _O = 0 V		±10	±13	V
Large signal voltage gain	V _{OS} = 0 V, V _I = 0 V, V _O = ±10 V, R _L ≥ 10 kΩ, T _A = 25°C		80	200	V/mV
Output voltage swing	V _{OS} = 0 V, R _L ≥ 10 kΩ, T _A = 25°C		±10	±14	V

Summary: ATE & Test categories

Automatic Test Equipment (ATE)

- Test equipment's that send automatic test pattern generation (ATPG) to the device under test (DUT).
- Major test categories:
 - ✓ Parametric Tests: measures current (or voltage) from the unit to ensure the circuits are functioning within specified parameters.
 - ✓ Functional Tests: evaluate functionality of the unit under operating conditions.
 - ✓ Speed Tests: assesses speed of units according to data sheet specifications. Sorting is done based on speed.
- **Yield, Testing Time and Test coverage** are key performance indicator during testing.

[Video: ATE at different stages](#)

